



Vishay High Power Products

Power Silicon Rectifier Diodes, 35 A/40 A/60 A



DO-203AB (DO-5)

35 A/40 A/60 A

DESCRIPTION/FEATURES



- · Good surge current capability up to 1000 A
- · Can be supplied to meet stringent military, aerospace and other high reliability requirements
- · RoHS compliant

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
1		35 ⁽¹⁾	35 (1)	40 (1)	60 ⁽¹⁾	Α	
I _{F(AV)}	T _C	140 (1)	140 (1)	150 ⁽¹⁾	140 ⁽¹⁾	°C	
I _{FSM}	50 Hz	480	380	765	860	А	
	60 Hz	500 ⁽¹⁾	400 (1)	800 (1)	900 (1)		
I ² t	50 Hz	1140	730	2900	3700	A ² s	
1-1	60 Hz 1040 670 2650	2650	3400	A-S			
I ² √t		16 100	10 300	41 000	52 500	A ² √s	
V _{RRM}	Range	50 to 600 ⁽¹⁾	700 to 1000 ⁽¹⁾	50 to 600 ⁽¹⁾	50 to 600 ⁽¹⁾	V	

PRODUCT SUMMARY

I_{F(AV)}

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER (3)		V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE V $T_J = -65~^{\circ}\text{C}$ TO 200 $^{\circ}\text{C}$ $^{(2)}$			
		$T_J = -65 ^{\circ}\text{C TO } 200 ^{\circ}\text{C} ^{(2)}$				
1N1183	1N1183A	1N2128A	50 ⁽¹⁾	50 ⁽¹⁾		
1N1184	1N1184A	1N2129A	100 (1)	100 (1)		
1N1185	1N1185A	1N2130A	150 ⁽¹⁾	150 ⁽¹⁾		
1N1186	1N1186A	1N2131A	200 (1)	200 (1)		
1N1187	1N1187A	1N2133A	300 (1)	300 (1)		
1N1188	1N1188A	1N2135A	400 (1)	400 (1)		
1N1189	1N1189A	1N2137A	500 ⁽¹⁾	500 ⁽¹⁾		
1N1190	1N1190A	1N2138A	600 (1)	600 ⁽¹⁾		
1N3765			700 (1)	700 ⁽¹⁾		
1N3766			800 (1)	800 (1)		
1N3767			900 (1)	900 (1)		
1N3768			1000 (1)	1000 (1)		

Notes

- (1) JEDEC registered values
- $^{(2)}$ For 1N1183 Series and 1N3765 Series T_{C} = 65 to 190 $^{\circ}C$
- (3) Basic part number indicates cathode to case. For anode to case, add "R" to part number, i.e., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA

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⁽¹⁾ JEDEC registered values

1N1183, 1N3765, 1N1183A, 1N2128A Series



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FORWARD CONDUCTION	ON							
PARAMETER	SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward current	I _{F(AV)}	1-phase operation, 180° sinusoidal conduction		35 ⁽¹⁾	35 ⁽¹⁾	40 (1)	60 ⁽¹⁾	Α
at case temperature				140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	480	380	765	860	A
Maximum peak one cycle		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	
non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with ½ V _{RRM} applied following surge = 0	570	455	910	1000	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		595	475	950	1050	
Maximum I ² t for fusing	— l ² t	t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = T_J$ maximum With $V_{RRM} = 0$ following surge, initial $T_J = T_J$ maximum	1140	730	2900	3700	- A ² s
Maximum i-t for fusing		t = 8.3 ms		1040	670	2650	3400	
Maximum I ² t for individual		t = 10 ms		1610	1030	4150	5250	
device fusing		t = 8.3 ms		1470	940	3750	4750	
Maximum I ² √t for individual device fusing	I ² √t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage	V	/ _{FM} T _J = 25 °C		1.7 (1)	1.8 (1)	1.3 (1)	1.3 (1)	٧
at maximum forward current (I_{FM})	V FM			110	110	126	188	Α
V _{RRM} = 700	-	Maximum and T		-	5.0 (1)	-	-	mA
V _{RRM} = 800				-	4.0 (1)	-	-	
Maximum average reverse current $V_{RRM} = 900$	$I_{R(AV)}$ Maximum rated $I_{F(AV)}$ and T_{C}		_{4V)} απα το	-	3.0 (1)	-	-	
V _{RRM} = 1000				-	2.0 (1)	-	-	
		Maximum rated $I_{F(AV)}$, V_{RRM} and T_{C}		10 ⁽¹⁾	-	2.5 (1)	10 ⁽¹⁾	

Notes

⁽¹⁾ JEDEC registered values

⁽²⁾ I²t for time $t_x = I^2 \sqrt{t} \times \sqrt{t_x}$



1N1183, 1N3765, 1N1183A, 1N2128A Series

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum operating case temperature range		T _C		- 65 to 190 ⁽¹⁾		- 65 to 200		°C
Maximum storage temperature range		T _{Stg}		- 65 to 175 ⁽¹⁾		- 65 to 200		
Maximum internal thermal resistance, junction to case		R _{thJC}	DC operation	1.00 (1)		1.1 (1)	0.65 (1)	°C/W
Thermal resistance, case to sink		R _{thCS}	Mounting surface, smooth, flat and greased	0.25		*C/VV		
minimum			Non-lubricated threads	2.3 (20)				N · m
Mounting torque -	maximum		Non-lubricated trireads	3.4 (30)				(lbf · in)
Approximate weight				17				g
				0.6				OZ.
Case style			JEDEC		DC	D-203AB (DC	D-5)	

Note

(1) JEDEC registered values

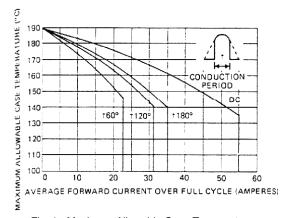


Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

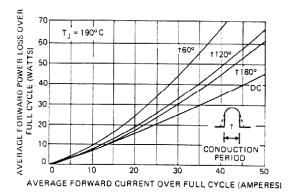


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

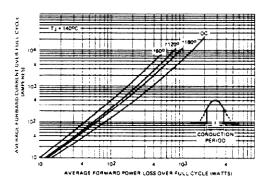


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

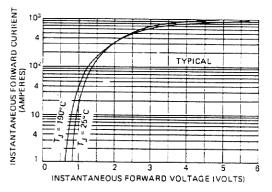


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

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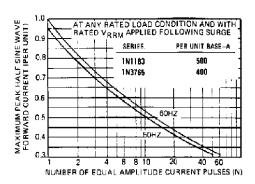


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series

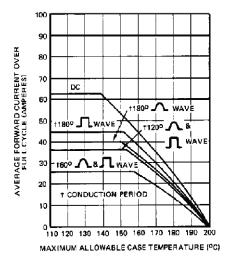


Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series

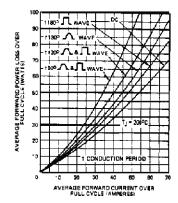


Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

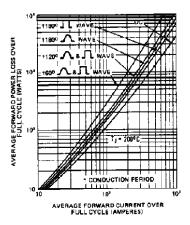


Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

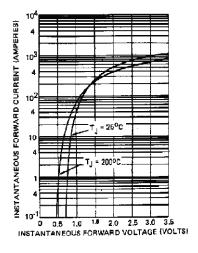


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

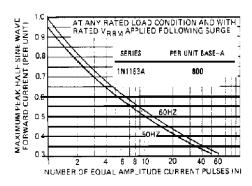


Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series





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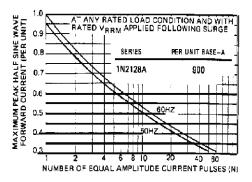


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series

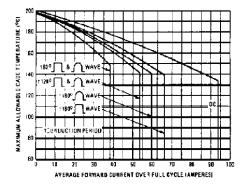


Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series

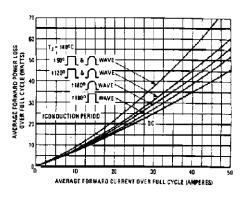


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

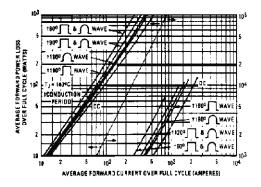


Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

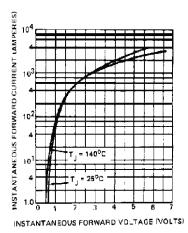


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95360			

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For technical questions, contact: ind-modules@vishay.com



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